

UNISONIC TECHNOLOGIES CO., LTD

UFR10030C

FAST RECOVERY EPITAXIAL DIODE

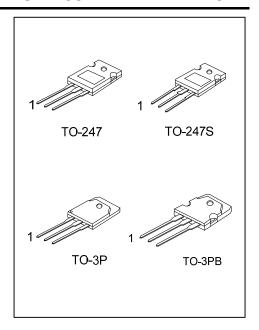
ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

DESCRIPTION

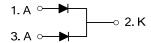
The UTC **UFR10030C** utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.

■ FEATURES

- * Ultrafast Recovery Time
- * Soft Recovery Characteristics
- * Low Recovery Loss
- * Low Forward Voltage
- * High Surge Current Capability
- * Low Leakage Current



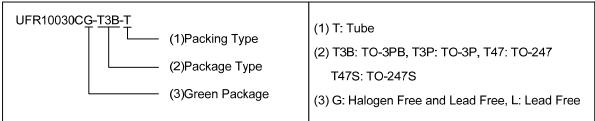
■ SYMBOL



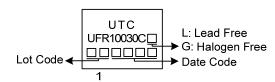
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UFR10030CL-T3B-T	UFR10030CG-T3B-T	TO-3PB	Α	K	Α	Tube	
UFR10030CL-T3P-T	UFR10030CG-T3P-T	TO-3P	Α	K	Α	Tube	
UFR10030CL-T47-T	UFR10030CG-T47-T	TO-247	Α	K	Α	Tube	
UFR10030CL-T47S-T	UFR10030CG-T47S-T	TO-247S	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



www.unisonic.com.tw 1 of 4

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Maximum D.C. Reverse Voltage		V_R	300	V
Maximum Peak Repetitive Reverse Voltage		V_{RRM}	300	V
Maximum Working Peak Reverse Voltage		V_{RWM}	300	V
Maximum Average Forward Current	Per Leg		50	Α
(T _C =110°C)	Total	I _{F(AV)}	100	Α
Non-Repetitive Forward Surge Current (T _J =45°C, t=10ms, 50Hz, Sine)		I _{FSM}	300	А
Operating Temperature Range		TJ	-40 ~ +150	°C
Storage Temperature Range		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	0.8	°C/W

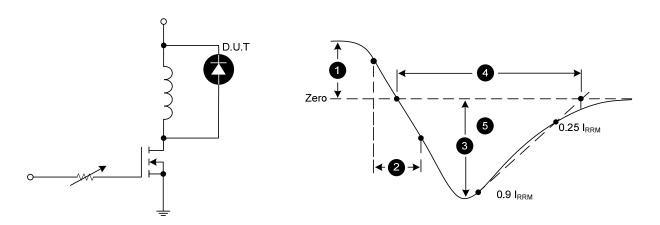
■ STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Famourd Valtage	.,	I _F =50A			1.3	V
Forward Voltage	V_F	I _F =50A, T _J =125°C			1.2	V
Maximum Reverse Leakage Current	I _{PM}	V _R =300V			1	μΑ
		V _R =300V, T _{.i} =125°C			100	uА

DYNAMIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Recovery Time	T _{rr}	I_F =1A, di _F /dt=-100A/ μ s, V_R =200V		36		ns
Reverse Recovery Time	t _{ee}	I _F =30A, di _F /dt=-100A/μs, V _R =200V		57		ns

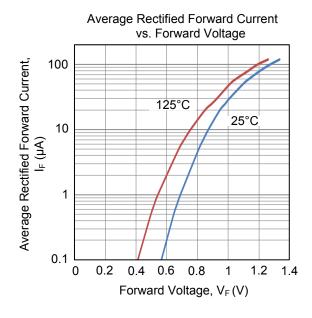
■ TEST CIRCUITS AND WAVEFORMS

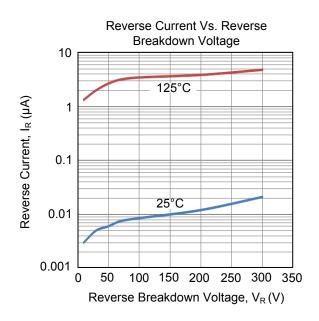


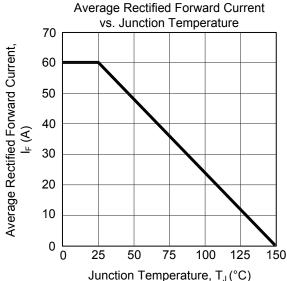
Diode Reverse Recovery Test Circuit and Waveform

- 1. I_F Forward Conduction Current
- 2. di_F/dt Rate of Diode Current Change Through Zero Crossing.
- 3. I_{RRM} Maximum Reverse Recovery Current.
- 4. t_{rr} Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through I_{RRM} and $0.25 \cdot I_{RRM}$ passes through zero.
- 5. Qrr Area Under the Curve Defined by I_{RRM} and $t_{\text{rr}}.$

■ TYPICAL CHARACTERISTICS







UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.